

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	3526	"magnetic memory"	USPAT	OR	OFF	2005/02/04 07:30
S2	638	S1 and "magnetic layer"	USPAT	OR	OFF	2005/02/04 07:31
S3	58	S2 and free and pin	USPAT	OR	OFF	2005/02/04 07:31
S4	27	S3 and soft	USPAT	OR	OFF	2005/02/04 07:31
S5	9	S4 and magneto-resistance	USPAT	OR	OFF	2005/02/04 09:45
S6	7166	"soft magnetic"	USPAT	OR	ON	2005/02/04 10:51
S7	271	S6 and "magnetic memory"	USPAT	OR	ON	2005/02/04 10:52
S8	55	S7 and "free layer"	USPAT	OR	ON	2005/02/04 10:53
S9	43	S8 and pin\$3	USPAT	OR	ON	2005/02/04 13:13
S10	28	S9 and tunnel	USPAT	OR	ON	2005/02/04 10:53
S11	0	S10 and anti-ferroelectric	USPAT	OR	ON	2005/02/04 10:54
S12	10	S10 and anti-ferromagnetic	USPAT	OR	ON	2005/02/04 10:54
S13	4	(("5940309") or ("5956267")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/04 13:14